











SN54AHCT245, **SN74AHCT245**

SCLS233P-OCTOBER 1995-REVISED JULY 2014

SNx4AHCT245 Octal Bus Transceivers With 3-State Outputs

Features

- Inputs Are TTL-Voltage Compatible
- Latch-Up Performance Exceeds 250 mA Per JESD 17
- ESD Protection Exceeds JESD 22
 - 2000-V Human-Body Model (A114-A)
 - 200-V Machine Model (A115-A)
 - 1000-V Charged-Device Model (C101)
- On Products Compliant to MIL-PRF-38535, All Parameters Are Tested Unless Otherwise Noted. On All Other Products, Production Processing Does Not Necessarily Include Testing of All Parameters.

2 Applications

- Servers
- PCs and Notebooks
- **Network Switches**
- Wearable Health and Fitness Devices
- Telecom Infrastructures
- Electronic Points of Sale

3 Description

The SNx4AHCT245 octal bus transceivers are designed for asynchronous two-way communication between data buses. These parts operate from 4.5 V to 5.5 V.

Device Information⁽¹⁾

PART NUMBER	PACKAGE	BODY SIZE (NOM)		
	PDIP (20)	25.40 x 6.35 mm		
	SOP (20)	12.60 x 5.30 mm		
SNx4AHCT245	SSOP (20)	7.50 x 5.30 mm		
	TVSOP (20)	5.00 x 4.40 mm		
	SOIC (20)	12.80 x 7.50 mm		

(1) For all available packages, see the orderable addendum at the end of the data sheet.

Simplified Schematic

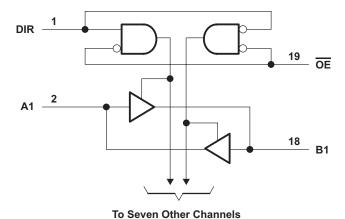




Table of Contents

1	Features 1		9.1 Overview
2	Applications 1		9.2 Functional Block Diagram
3	Description 1		9.3 Feature Description
4	Simplified Schematic 1		9.4 Device Functional Modes
5	Revision History	10	Application and Implementation
6	Pin Configuration and Functions		10.1 Application Information
7	Specifications		10.2 Typical Application
′	7.1 Absolute Maximum Ratings	11	Power Supply Recommendations 1
	7.1 Absolute Maximum Ratings	12	Layout 1
	7.3 Recommended Operating Conditions		12.1 Layout Guidelines 1
	7.4 Thermal Information		12.2 Layout Example 1
	7.5 Electrical Characteristics 5	13	Device and Documentation Support 1
	7.6 Switching Characteristics 6		13.1 Related Links 1
	7.7 Noise Characteristics		13.2 Trademarks 1
	7.8 Operating Characteristics		13.3 Electrostatic Discharge Caution 1
	7.9 Typical Characteristics		13.4 Glossary 1
8 9	Parameter Measurement Information	14	Mechanical, Packaging, and Orderable Information
9	Detailed Description 0		

5 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

Changes from Revision O (August 2013) to Revision P	Page
Updated document to new TI data sheet format	1
Added Military Disclaimer to Features list.	1
Added Applications	1
Added Pin Functions table	3
Added Handling Ratings table	4
Added Thermal Information table	5
Added Typical Characteristics.	6
Added Detailed Description section	8
Added Application and Implementation section	9

CI	hanges from Revision N (March 2005) to Revision O	Page
•	Removed Ordering Information table.	1
•	Extended operating temperature range to 125°C	4

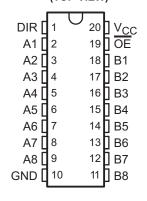
Submit Documentation Feedback

Copyright © 1995–2014, Texas Instruments Incorporated

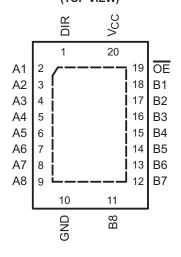


6 Pin Configuration and Functions

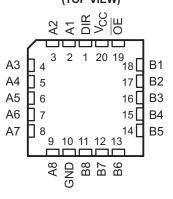
SN54AHCT245 . . . J OR W PACKAGE SN74AHCT245 . . . DB, DGV, DW, N, NS, OR PW PACKAGE (TOP VIEW)



SN74AHCT245 . . . RGY PACKAGE (TOP VIEW)



SN54AHCT245 . . . FK PACKAGE (TOP VIEW)



Pin Functions

	PIN	1/0	DECODIDETION				
NO.	NAME	I/O	DESCRIPTION				
1	DIR	_	Direction Pin				
2	A1	I/O	A1 Input/Output				
3	A2	I/O	A2 Input/Output				
4	A3	I/O	A3 Input/Output				
5	A4	I/O	A4 Input/Output				
6	A5	I/O	A5 Input/Output				
7	A6	I/O	A6 Input/Output				
8	A7	I/O	A7 Input/Output				
9	A8	I/O	A8 Input/Output				
10	GND	_	Ground Pin				
11	B8	I/O	B8 Input/Output				
12	B7	I/O	B7 Input/Output				
13	B6	I/O	B6 Input/Output				
14	B5	I/O	B5 Input/Output				
15	B4	I/O	B4 Input/Output				
16	В3	I/O	B3 Input/Output				
17	B2	I/O	B2 Input/Output				
18	B1	I/O	B1 Input/Output				
19	ŌĒ	I	Output Enable				
20	VCC	_	Power Pin				



7 Specifications

7.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)⁽¹⁾

				MIN	MAX	UNIT
V_{CC}	Supply voltage range	-0.5	7	V		
V_{I}	Input voltage range (2)	Control inputs	-0.5	7	V	
Vo	Output voltage range (2)				V _{CC} + 0.5	V
I _{IK}	Input clamp current	V _I < 0	Control inputs		-20	mA
I _{OK}	Output clamp current	$V_O < 0$ or $V_O > V_{CC}$			±20	mA
Io	Continuous output current	$V_O = 0$ to V_{CC}			±25	mA
	Continuous current through V_{CC} or GND	_			±75	mA

⁽¹⁾ Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under Recommended Operating Conditions is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

7.2 Handling Ratings

			MIN	MAX	UNIT	
T _{stg}	Storage temperature rang	- 65	150	°C		
V	Electrostatic discharge	Human body model (HBM), per ANSI/ESDA/JEDEC JS-001, all pins (1)	0	2000	\/	
V _(ESD)	Electrostatic discharge	Charged device model (CDM), per JEDEC specification JESD22-C101, all pins (2)	0	1000	V	

⁽¹⁾ JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.

7.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)(1)

		SN54AHCT245		SN74AHC	T245	UNIT
		MIN	MAX	MIN	MIN MAX	
V_{CC}	Supply voltage	4.5	5.5	4.5	5.5	V
V_{IH}	High-level input voltage	2		2		V
V_{IL}	Low-level Input voltage		8.0		0.8	V
VI	Input voltage	0	5.5	0	5.5	V
Vo	Output voltage	0	V_{CC}	0	V _{CC}	V
I _{OH}	High-level output current		-8		-8	mA
I _{OL}	Low-level output current		8		8	mA
Δt/Δν	Input Transition rise and fall rate		20		20	ns/V
T _A	Operating free-air temperature	-55	125	-40	125	°C

⁽¹⁾ All unused inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.

²⁾ The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

⁽²⁾ JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.



7.4 Thermal Information

				8	N74AHCT245						
	THERMAL METRIC ⁽¹⁾	DB	DGV	DW	N	NS	PW	RGY	UNIT		
			20 PINS								
$R_{\theta JA}$	Junction-to-ambient thermal resistance	96.0	116.1	79.8	51.5	77.1	102.8	35.1			
$R_{\theta JC(top)}$	Junction-to-case (top) thermal resistance	57.7	31.3	45.8	38.2	43.6	36.8	43.3			
$R_{\theta JB}$	Junction-to-board thermal resistance	51.2	57.6	47.4	32.4	44.6	53.8	12.9			
Ψлт	Junction-to-top characterization parameter	19.4	1.0	18.5	24.6	17.2	2.5	0.9	°C/W		
ΨЈВ	Junction-to-board characterization parameter	50.8	56.9	47.0	32.3	44.2	53.3	12.9			
$R_{\theta JC(bot)}$	Junction-to-case (bottom) thermal resistance	n/a	n/a	n/a	n/a	n/a	n/a	7.9			

⁽¹⁾ For more information about traditional and new thermal metrics, see the IC Package Thermal Metrics application report, SPRA953.

7.5 Electrical Characteristics

over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER		TEST CONDITIONS	V _{cc}	T,	_A = 25°C	;	SN54AHC -55°C TO 1		SN74AH -40°C TO		Recomm SN74AH -40°C TO	CT245	UNIT
				MIN	TYP	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
\/		$I_{OH} = -50 \mu A$	4.5 V	4.4	4.5		4.4		4.4		4.4		V
V _{OH}		$I_{OH} = -8 \text{ mA}$	4.5 V	3.94			3.8		3.8		3.7		v
		I _{OL} = 50 μA	4.5 V			0.1		0.1		0.1		0.1	V
V _{OL}		I _{OH} = 8 mA	4.5 V			0.36		0.44		0.44		0.44	v
I _I	OE or DIR	V _I = 5.5 V or GND	0 to 5.5 V			±0.1		±1 ⁽¹⁾		±1		±1	μΑ
I _{OZ}	A or B inputs (2)	V _O = V _{CC} or GND	5.5 V			±.25		±2.5		±2.5		±2.5	μΑ
I _{CC}		$V_I = V_{CC}$ or GND, $I_O = 0$	5.5 V			4		40		40		40	μA
ΔI _{CC} ⁽³⁾		One input at 3.4 V, Other inputs at V _{CC} or GND	5.5 V			1.35		1.5		1.5		1.5	mA
Ci	OE or DIR	V _I = V _{CC} or GND	5 V		2.5	10				10			pF
C _{io}	A or B inputs	V _I = V _{CC} or GND	5 V		4								pF

On products compliant to MIL-PRF-38535, this parameter is not production tested at V_{CC} = 0 V.

For I/O ports, the parameter I_{OZ} includes the input leakage current. This is the increase in supply current for each input at one of the specified TTL voltage levels, rather than 0 V or V_{CC} .

STRUMENTS

Switching Characteristics

over recommended operating free-air temperature range, V_{CC} = 5 V ± 0.5 V (unless otherwise noted) (see Figure 2)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	LOAD CAPACITANCE			25°C	SN54AH -55°C TO		SN74AI -40°C T		Recomm SN74AH -40°C TC	CT245	UNIT
				TYP	MAX	MIN	MAX	MIN	MAX	MIN	MAX		
t _{PLH}	A or B	B or A	C 45 pF	4.5 ⁽¹⁾	7.7 ⁽¹⁾	1 ⁽¹⁾	10 ⁽¹⁾	1	8.5	1	10		
t _{PHL}	AOIB	BOIA	$C_L = 15 pF$	4.5 ⁽¹⁾	7.7 ⁽¹⁾	1 ⁽¹⁾	10 ⁽¹⁾	1	8.5	1	10	ns	
t _{PZH}	ŌĒ	A or D	C 45 pF	8.9 ⁽¹⁾	13.8 ⁽¹⁾	1 ⁽¹⁾	16 ⁽¹⁾	1	15	1	16		
t _{PZL}	OE	A OF B	A or B	$C_L = 15 pF$	8.9 ⁽¹⁾	13.8 ⁽¹⁾	1 ⁽¹⁾	16 ⁽¹⁾	1	15	1	16	ns
t _{PHZ}	ŌĒ	A or B	C _L = 15 pF	9.2 ⁽¹⁾	14.4 ⁽¹⁾	1 ⁽¹⁾	16.5 ⁽¹⁾	1	15.5	1	16.5	ns	
t _{PLZ}	OE	A or B		9.2 ⁽¹⁾	14.4 ⁽¹⁾	1 ⁽¹⁾	16.5 ⁽¹⁾	1	15.5	1	16.5	3.5	
t _{PLH}	A or B	B or A	C - 50 pF	5.3	8.7	1	11	1	9.5	1	11		
t _{PHL}	AOIB	BOIA	$C_L = 50 \text{ pF}$	5.3	8.7	1	11	1	9.5	1	11	ns	
t _{PZH}	OF.	A or B	C 50 pF	9.7	14.8	1	17	1	16	1	17		
t _{PZL}	- ŌE	AOIB	$C_L = 50 \text{ pF}$	9.7	14.8	1	17	1	16	1	17	ns	
t _{PHZ}	ŌĒ	A or B	C - 50 pF	10	15.4	1	17.5	1	16.5	1	17.5	no	
t _{PLZ}	OE .	AUID	C _L = 50 pF	10	15.4	1	17.5	1	16.5	1	17.5	ns	
t _{sk(o)}			C _L = 50 pF		1 ⁽²⁾				1			ns	

⁽¹⁾ On products compliant to MIL-PRF-38535, this parameter is not production tested.(2) On products compliant to MIL-PRF-38535, this parameter does not apply.

7.7 Noise Characteristics

 $V_{CC} = 5 \text{ V}, C_L = 50 \text{ pF}, T_A = 25^{\circ}\text{C}^{(1)}$

PARAMETER			SN74AHCT245				
	PARAMETER	MIN	TYP	MAX	UNIT		
V _{OH(V)}	Quiet output, minimum dynamic V _{OH}		4		V		
$V_{IH(D)}$	High-level dynamic input voltage	2			V		
$V_{IL(D)}$	Low-level dynamic input voltage			0.8	V		

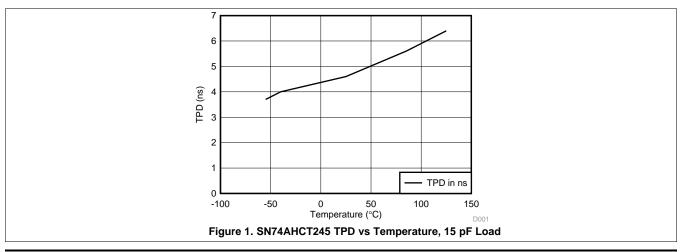
⁽¹⁾ Characteristics are for surface-mount packages only.

7.8 Operating Characteristics

 $V_{CC} = 5 \text{ V}, T_A = 25^{\circ}\text{C}$

	PARAMETER	TEST CO	NDITIONS	TYP	UNIT
C_{pd}	Power dissipation capacitance	No load,	f = 1 MHz	13	pF

7.9 Typical Characteristics

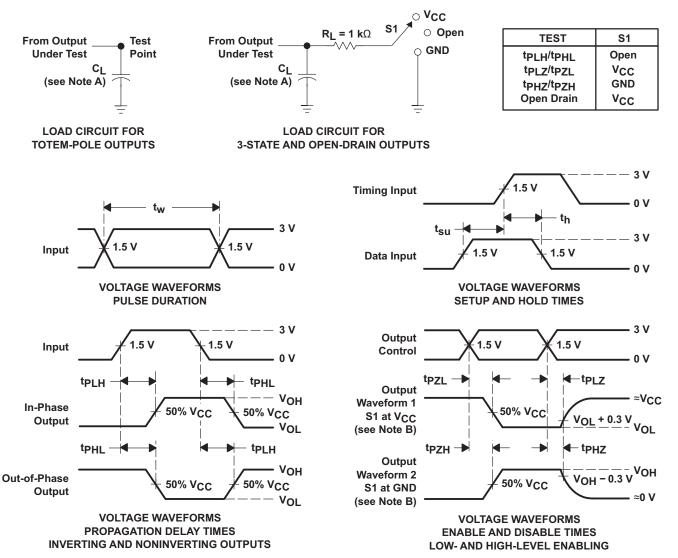


Submit Documentation Feedback

Copyright © 1995-2014, Texas Instruments Incorporated



8 Parameter Measurement Information



- A. C_L includes probe and jig capacitance.
- B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output
 - Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control
- C. All input pulses are supplied by generators having the following characteristics: PRR \leq 1 MHz, $Z_O = 50 \Omega$, $t_f \leq$ 3 ns. $t_f \leq$ 3 ns.
- D. The outputs are measured one at a time with one input transition per measurement.
- E. All parameters and waveforms are not applicable to all devices.

Figure 2. Load Circuit and Voltage Waveforms

Submit Documentation Feedback



9 Detailed Description

9.1 Overview

The SNx7ACHT245 octal bus transceivers are designed for asynchronous two-way communication between data buses. The control-function implementation minimizes external timing requirements. The SNx4AHCT245 devices allow data transmission from the A bus to the B bus or from the B bus to the A bus, depending on the logic level at the direction—control (DIR) input. The output-enable ($\overline{\text{OE}}$) input can be used to disable the device so that the buses effectively are isolated. To ensure the high-impedance state during power up or power down, $\overline{\text{OE}}$ should be tied to V_{CC} through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

9.2 Functional Block Diagram

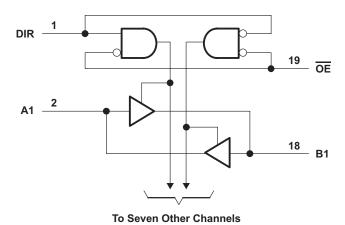


Figure 3. Logic Diagram (Positive Logic)

9.3 Feature Description

- V_{CC} is optimized at 5 V
- Allows up voltage translation from 3.3 V to 5 V
 - Inputs Accept V_{IH} levels of 2 V
- Slow edge rates minimize output ringing

9.4 Device Functional Modes

Table 1. Function Table (Each Transceiver)

INP	UTS	OPERATION			
OE	DIR	OPERATION			
L	L	B data to A bus			
L	Н	A data to B bus			
Н	Χ	Isolation			

Submit Documentation Feedback



10 Application and Implementation

10.1 Application Information

The SN74AHCT245 is a low drive CMOS device that can be used for a multitude of bus interface type applications where output ringing is a concern. The low drive and slow edge rates will minimize overshoot and undershoot on the outputs. The input switching levels have been lowered to accommodate TTL inputs of 0.8 V V_{IL} and 2 V V_{IH} . This feature makes it ideal for translating up from 3.3 V to 5 V. The figure below shows this type of translation.

10.2 Typical Application

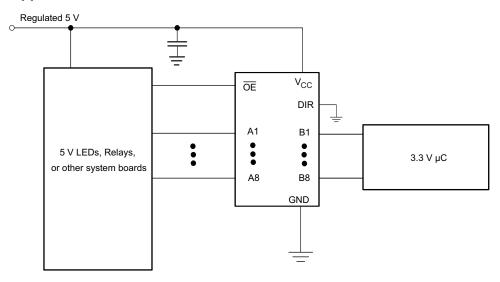


Figure 4. Typical Application Diagram

10.2.1 Design Requirements

This device uses CMOS technology and has balanced output drive. Care should be taken to avoid bus contention because it can drive currents that would exceed maximum limits. The high drive will also create fast edges into light loads so routing and load conditions should be considered to prevent ringing.

10.2.2 Detailed Design Procedure

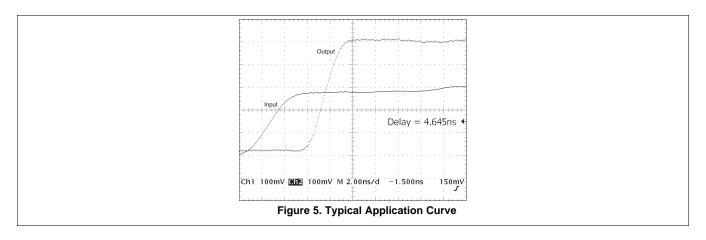
- Recommended input conditions
 - Specified high and low levels. See (V_{IH} and V_{IL}) in the Recommended Operating Conditions table.
 - Specified high and low levels. See (V_{IH} and V_{IL}) in the Recommended Operating Conditions table.
 - Inputs are overvoltage tolerant allowing them to go as high as 5.5 V at any valid V_{CC}
- · Recommend output conditions
 - Load currents should not exceed 25 mA per output and 50 mA total for the part
 - Outputs should not be pulled above V_{CC}

Submit Documentation Feedback



Typical Application (continued)

10.2.3 Application Curves



11 Power Supply Recommendations

The power supply can be any voltage between the MIN and MAX supply voltage rating located in the *Recommended Operating Conditions* table.

Each VCC pin should have a good bypass capacitor to prevent power disturbance. For devices with a single supply, 0.1 μ f is recommended; if there are multiple VCC pins, then 0.01 μ f or 0.022 μ f is recommended for each power pin. It is acceptable to parallel multiple bypass caps to reject different frequencies of noise. A 0.1 μ f and a 1 μ f are commonly used in parallel. The bypass capacitor should be installed as close to the power pin as possible for best results.

12 Layout

12.1 Layout Guidelines

When using multiple-bit logic devices, inputs should never float.

In many cases, functions or parts of functions of digital logic devices are unused, for example, when only two inputs of a triple-input AND gate are used or only 3 of the 4 buffer gates are used. Such input pins should not be left unconnected because the undefined voltages at the outside connections result in undefined operational states. Figure 6 specifies the rules that must be observed under all circumstances. All unused inputs of digital logic devices must be connected to a high or low bias to prevent them from floating. The logic level that should be applied to any particular unused input depends on the function of the device. Generally they will be tied to GND or $V_{\rm CC}$, whichever makes more sense or is more convenient. It is generally acceptable to float outputs, unless the part is a transceiver. If the transceiver has an output enable pin, it will disable the output section of the part when asserted. This will not disable the input section of the I/Os, so they cannot float when disabled.

12.2 Layout Example

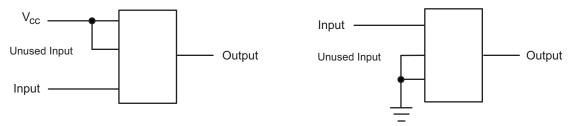


Figure 6. Layout Diagram

0 Submit Documentation Feedback

Copyright © 1995–2014, Texas Instruments Incorporated



13 Device and Documentation Support

13.1 Related Links

The table below lists quick access links. Categories include technical documents, support and community resources, tools and software, and quick access to sample or buy.

Table 2. Related Links

PARTS	PRODUCT FOLDER	SAMPLE & BUY	TECHNICAL DOCUMENTS	TOOLS & SOFTWARE	SUPPORT & COMMUNITY	
SN54AHCT245	Click here	Click here	Click here	Click here	Click here	
SN74AHCT245	Click here	Click here	Click here	Click here	Click here	

13.2 Trademarks

All trademarks are the property of their respective owners.

13.3 Electrostatic Discharge Caution



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

13.4 Glossary

SLYZ022 — TI Glossary.

This glossary lists and explains terms, acronyms, and definitions.

14 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.





16-Jul-2014

PACKAGING INFORMATION

Orderable Device	Status	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
5962-9681901Q2A	ACTIVE	LCCC	FK	20	1	TBD	(6) POST-PLATE	N / A for Pkg Type	-55 to 125	5962- 9681901Q2A SNJ54AHCT 245FK	Samples
5962-9681901QRA	ACTIVE	CDIP	J	20	1	TBD	A42	N / A for Pkg Type	-55 to 125	5962-9681901QR A SNJ54AHCT245J	Samples
5962-9681901QSA	ACTIVE	CFP	W	20	1	TBD	A42	N / A for Pkg Type	-55 to 125	5962-9681901QS A SNJ54AHCT245W	Samples
SN74AHCT245DBLE	OBSOLETE	SSOP	DB	20		TBD	Call TI	Call TI	-40 to 125		
SN74AHCT245DBR	ACTIVE	SSOP	DB	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	HB245	Samples
SN74AHCT245DBRG4	ACTIVE	SSOP	DB	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	HB245	Samples
SN74AHCT245DGVR	ACTIVE	TVSOP	DGV	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	HB245	Samples
SN74AHCT245DW	ACTIVE	SOIC	DW	20	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	AHCT245	Samples
SN74AHCT245DWG4	ACTIVE	SOIC	DW	20	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	AHCT245	Samples
SN74AHCT245DWR	ACTIVE	SOIC	DW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	AHCT245	Samples
SN74AHCT245DWRG4	ACTIVE	SOIC	DW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	AHCT245	Samples
SN74AHCT245N	ACTIVE	PDIP	N	20	20	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	-40 to 125	SN74AHCT245N	Samples
SN74AHCT245NSR	ACTIVE	SO	NS	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	AHCT245	Samples
SN74AHCT245PW	ACTIVE	TSSOP	PW	20	70	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	HB245	Samples
SN74AHCT245PWE4	ACTIVE	TSSOP	PW	20	70	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	HB245	Samples
SN74AHCT245PWG4	ACTIVE	TSSOP	PW	20	70	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	HB245	Samples



www.ti.com

PACKAGE OPTION ADDENDUM

16-Jul-2014

Orderable Device	Status	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
SN74AHCT245PWLE	OBSOLETE	TSSOP	PW	20		TBD	Call TI	Call TI	-40 to 125		
SN74AHCT245PWR	ACTIVE	TSSOP	PW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU CU SN	Level-1-260C-UNLIM	-40 to 125	HB245	Samples
SN74AHCT245PWRE4	ACTIVE	TSSOP	PW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	HB245	Samples
SN74AHCT245PWRG3	ACTIVE	TSSOP	PW	20	2000	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM	-40 to 125	HB245	Samples
SN74AHCT245PWRG4	ACTIVE	TSSOP	PW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	HB245	Samples
SN74AHCT245RGYR	ACTIVE	VQFN	RGY	20	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 125	HB245	Samples
SN74AHCT245RGYRG4	ACTIVE	VQFN	RGY	20	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 125	HB245	Samples
SNJ54AHCT245FK	ACTIVE	LCCC	FK	20	1	TBD	POST-PLATE	N / A for Pkg Type	-55 to 125	5962- 9681901Q2A SNJ54AHCT 245FK	Samples
SNJ54AHCT245J	ACTIVE	CDIP	J	20	1	TBD	A42	N / A for Pkg Type	-55 to 125	5962-9681901QR A SNJ54AHCT245J	Samples
SNJ54AHCT245W	ACTIVE	CFP	W	20	1	TBD	A42	N / A for Pkg Type	-55 to 125	5962-9681901QS A SNJ54AHCT245W	Samples

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes. **Pb-Free** (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

⁽²⁾ Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.





16-Jul-2014

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

- (3) MSL, Peak Temp. The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead/Ball Finish Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

Important Information and Disclaimer: The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

OTHER QUALIFIED VERSIONS OF SN54AHCT245. SN74AHCT245:

Catalog: SN74AHCT245

Military: SN54AHCT245

NOTE: Qualified Version Definitions:

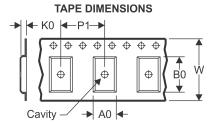
- Catalog TI's standard catalog product
- Military QML certified for Military and Defense Applications

PACKAGE MATERIALS INFORMATION

www.ti.com 27-Jun-2014

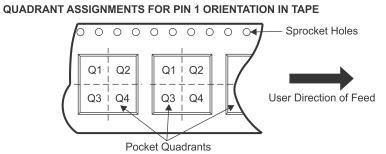
TAPE AND REEL INFORMATION





	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

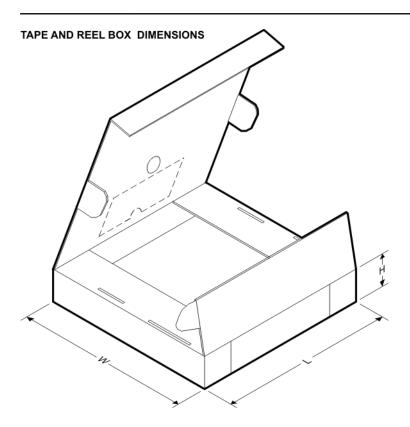
— Neel viidii (vvi)



*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74AHCT245DBR	SSOP	DB	20	2000	330.0	16.4	8.2	7.5	2.5	12.0	16.0	Q1
SN74AHCT245DGVR	TVSOP	DGV	20	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
SN74AHCT245DWR	SOIC	DW	20	2000	330.0	24.4	10.8	13.3	2.7	12.0	24.0	Q1
SN74AHCT245NSR	SO	NS	20	2000	330.0	24.4	8.2	13.0	2.5	12.0	24.0	Q1
SN74AHCT245PWR	TSSOP	PW	20	2000	330.0	16.4	6.95	7.1	1.6	8.0	16.0	Q1
SN74AHCT245PWR	TSSOP	PW	20	2000	330.0	16.4	6.95	7.1	1.6	8.0	16.0	Q1
SN74AHCT245PWRG3	TSSOP	PW	20	2000	330.0	16.4	6.95	7.1	1.6	8.0	16.0	Q1
SN74AHCT245RGYR	VQFN	RGY	20	3000	330.0	12.4	3.8	4.8	1.6	8.0	12.0	Q1

www.ti.com 27-Jun-2014



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74AHCT245DBR	SSOP	DB	20	2000	367.0	367.0	38.0
SN74AHCT245DGVR	TVSOP	DGV	20	2000	367.0	367.0	35.0
SN74AHCT245DWR	SOIC	DW	20	2000	367.0	367.0	45.0
SN74AHCT245NSR	SO	NS	20	2000	367.0	367.0	45.0
SN74AHCT245PWR	TSSOP	PW	20	2000	364.0	364.0	27.0
SN74AHCT245PWR	TSSOP	PW	20	2000	367.0	367.0	38.0
SN74AHCT245PWRG3	TSSOP	PW	20	2000	364.0	364.0	27.0
SN74AHCT245RGYR	VQFN	RGY	20	3000	367.0	367.0	35.0

14 LEADS SHOWN



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. This package is hermetically sealed with a ceramic lid using glass frit.
- D. Index point is provided on cap for terminal identification only on press ceramic glass frit seal only.
- E. Falls within MIL STD 1835 GDIP1-T14, GDIP1-T16, GDIP1-T18 and GDIP1-T20.

W (R-GDFP-F20)

CERAMIC DUAL FLATPACK



- A. All linear dimensions are in inches (millimeters).
- This drawing is subject to change without notice.
- C. This package can be hermetically sealed with a ceramic lid using glass frit.

 D. Index point is provided on cap for terminal identification only.

 E. Falls within Mil—Std 1835 GDFP2—F20



FK (S-CQCC-N**)

LEADLESS CERAMIC CHIP CARRIER

28 TERMINAL SHOWN



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. This package can be hermetically sealed with a metal lid.
- D. Falls within JEDEC MS-004



N (R-PDIP-T**)

PLASTIC DUAL-IN-LINE PACKAGE

16 PINS SHOWN



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Falls within JEDEC MS-001, except 18 and 20 pin minimum body length (Dim A).
- The 20 pin end lead shoulder width is a vendor option, either half or full width.



DGV (R-PDSO-G**)

24 PINS SHOWN

PLASTIC SMALL-OUTLINE



NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15 per side.

D. Falls within JEDEC: 24/48 Pins – MO-153 14/16/20/56 Pins – MO-194 DW (R-PDSO-G20)

PLASTIC SMALL OUTLINE



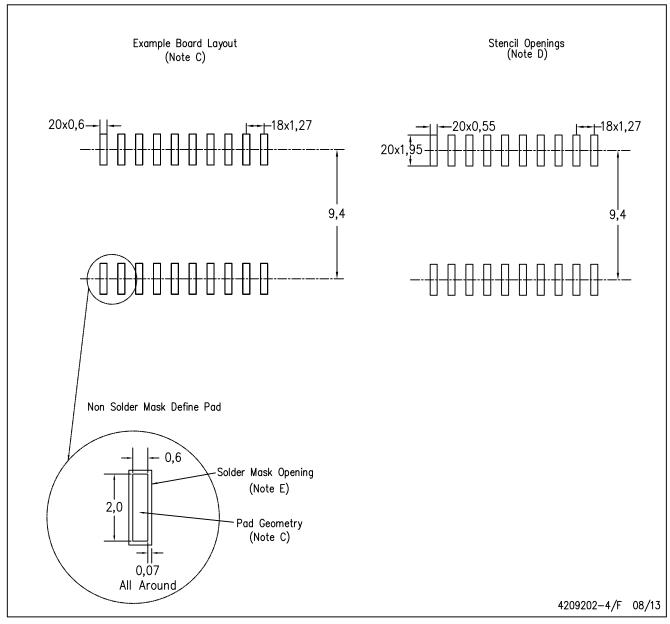
NOTES: A. All linear dimensions are in inches (millimeters). Dimensioning and tolerancing per ASME Y14.5M-1994.

- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0,15).
- D. Falls within JEDEC MS-013 variation AC.



DW (R-PDSO-G20)

PLASTIC SMALL OUTLINE



- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Refer to IPC7351 for alternate board design.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



PW (R-PDSO-G20)

PLASTIC SMALL OUTLINE

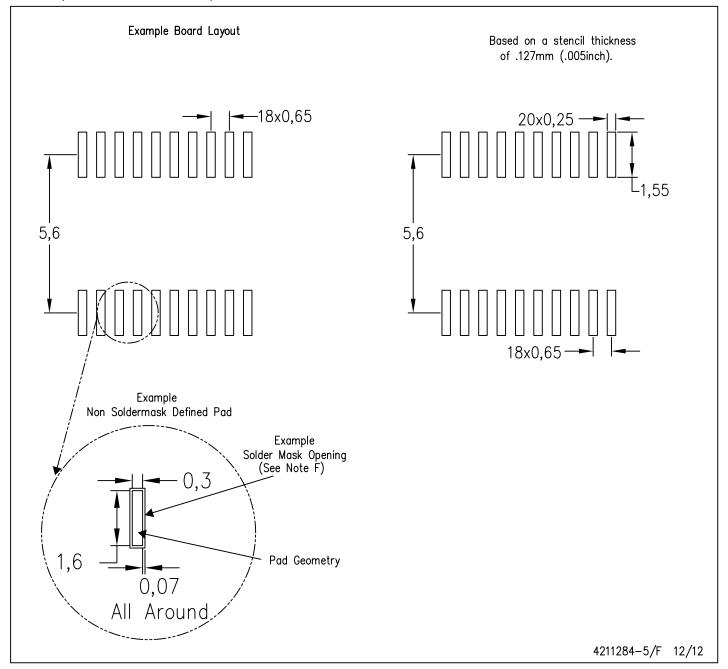


- A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M—1994.
- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0,15 each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0,25 each side.
- E. Falls within JEDEC MO-153



PW (R-PDSO-G20)

PLASTIC SMALL OUTLINE



- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate design.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



DB (R-PDSO-G**)

PLASTIC SMALL-OUTLINE

28 PINS SHOWN

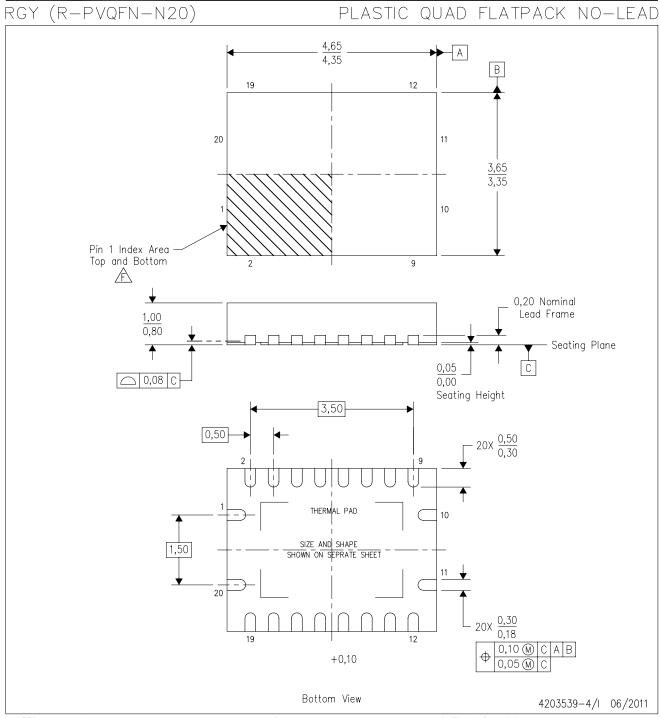


NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion not to exceed 0,15.

D. Falls within JEDEC MO-150



NOTES: A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.

- B. This drawing is subject to change without notice.
- C. QFN (Quad Flatpack No-Lead) package configuration.
- D. The package thermal pad must be soldered to the board for thermal and mechanical performance.
- E. See the additional figure in the Product Data Sheet for details regarding the exposed thermal pad features and dimensions.
- Pin 1 identifiers are located on both top and bottom of the package and within the zone indicated. The Pin 1 identifiers are either a molded, marked, or metal feature.
- G. Package complies to JEDEC MO-241 variation BA.



RGY (R-PVQFN-N20)

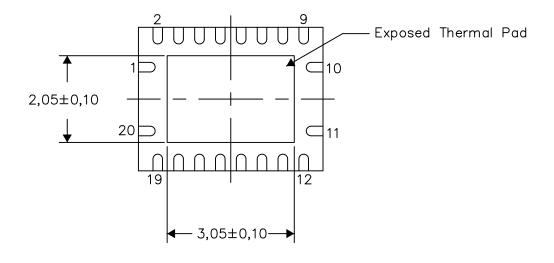
PLASTIC QUAD FLATPACK NO-LEAD

THERMAL INFORMATION

This package incorporates an exposed thermal pad that is designed to be attached directly to an external heatsink. The thermal pad must be soldered directly to the printed circuit board (PCB). After soldering, the PCB can be used as a heatsink. In addition, through the use of thermal vias, the thermal pad can be attached directly to the appropriate copper plane shown in the electrical schematic for the device, or alternatively, can be attached to a special heatsink structure designed into the PCB. This design optimizes the heat transfer from the integrated circuit (IC).

For information on the Quad Flatpack No-Lead (QFN) package and its advantages, refer to Application Report, QFN/SON PCB Attachment, Texas Instruments Literature No. SLUA271. This document is available at www.ti.com.

The exposed thermal pad dimensions for this package are shown in the following illustration.



Bottom View

Exposed Thermal Pad Dimensions

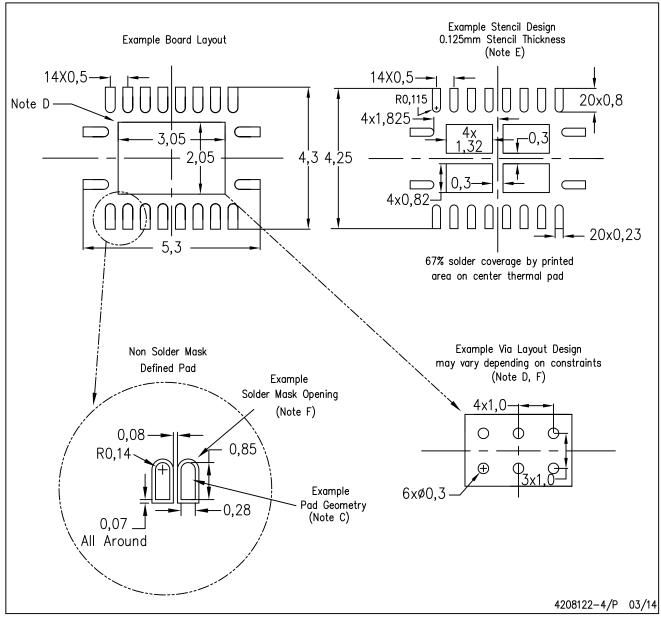
4206353-4/P 03/14

NOTE: All linear dimensions are in millimeters



RGY (R-PVQFN-N20)

PLASTIC QUAD FLATPACK NO-LEAD



- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. This package is designed to be soldered to a thermal pad on the board. Refer to Application Note, Quad Flat—Pack QFN/SON PCB Attachment, Texas Instruments Literature No. SLUA271, and also the Product Data Sheets for specific thermal information, via requirements, and recommended board layout. These documents are available at www.ti.com http://www.ti.com.
- E. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC 7525 for stencil design considerations.
- F. Customers should contact their board fabrication site for minimum solder mask web tolerances between signal pads.



MECHANICAL DATA

NS (R-PDSO-G**)

14-PINS SHOWN

PLASTIC SMALL-OUTLINE PACKAGE



- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15.



IMPORTANT NOTICE

Texas Instruments Incorporated and its subsidiaries (TI) reserve the right to make corrections, enhancements, improvements and other changes to its semiconductor products and services per JESD46, latest issue, and to discontinue any product or service per JESD48, latest issue. Buyers should obtain the latest relevant information before placing orders and should verify that such information is current and complete. All semiconductor products (also referred to herein as "components") are sold subject to TI's terms and conditions of sale supplied at the time of order acknowledgment.

TI warrants performance of its components to the specifications applicable at the time of sale, in accordance with the warranty in TI's terms and conditions of sale of semiconductor products. Testing and other quality control techniques are used to the extent TI deems necessary to support this warranty. Except where mandated by applicable law, testing of all parameters of each component is not necessarily performed.

TI assumes no liability for applications assistance or the design of Buyers' products. Buyers are responsible for their products and applications using TI components. To minimize the risks associated with Buyers' products and applications, Buyers should provide adequate design and operating safeguards.

TI does not warrant or represent that any license, either express or implied, is granted under any patent right, copyright, mask work right, or other intellectual property right relating to any combination, machine, or process in which TI components or services are used. Information published by TI regarding third-party products or services does not constitute a license to use such products or services or a warranty or endorsement thereof. Use of such information may require a license from a third party under the patents or other intellectual property of the third party, or a license from TI under the patents or other intellectual property of TI.

Reproduction of significant portions of TI information in TI data books or data sheets is permissible only if reproduction is without alteration and is accompanied by all associated warranties, conditions, limitations, and notices. TI is not responsible or liable for such altered documentation. Information of third parties may be subject to additional restrictions.

Resale of TI components or services with statements different from or beyond the parameters stated by TI for that component or service voids all express and any implied warranties for the associated TI component or service and is an unfair and deceptive business practice. TI is not responsible or liable for any such statements.

Buyer acknowledges and agrees that it is solely responsible for compliance with all legal, regulatory and safety-related requirements concerning its products, and any use of TI components in its applications, notwithstanding any applications-related information or support that may be provided by TI. Buyer represents and agrees that it has all the necessary expertise to create and implement safeguards which anticipate dangerous consequences of failures, monitor failures and their consequences, lessen the likelihood of failures that might cause harm and take appropriate remedial actions. Buyer will fully indemnify TI and its representatives against any damages arising out of the use of any TI components in safety-critical applications.

In some cases, TI components may be promoted specifically to facilitate safety-related applications. With such components, TI's goal is to help enable customers to design and create their own end-product solutions that meet applicable functional safety standards and requirements. Nonetheless, such components are subject to these terms.

No TI components are authorized for use in FDA Class III (or similar life-critical medical equipment) unless authorized officers of the parties have executed a special agreement specifically governing such use.

Only those TI components which TI has specifically designated as military grade or "enhanced plastic" are designed and intended for use in military/aerospace applications or environments. Buyer acknowledges and agrees that any military or aerospace use of TI components which have *not* been so designated is solely at the Buyer's risk, and that Buyer is solely responsible for compliance with all legal and regulatory requirements in connection with such use.

TI has specifically designated certain components as meeting ISO/TS16949 requirements, mainly for automotive use. In any case of use of non-designated products, TI will not be responsible for any failure to meet ISO/TS16949.

Products Applications

Audio www.ti.com/audio Automotive and Transportation www.ti.com/automotive Communications and Telecom Amplifiers amplifier.ti.com www.ti.com/communications **Data Converters** dataconverter.ti.com Computers and Peripherals www.ti.com/computers **DLP® Products** www.dlp.com Consumer Electronics www.ti.com/consumer-apps

DSP **Energy and Lighting** dsp.ti.com www.ti.com/energy Clocks and Timers www.ti.com/clocks Industrial www.ti.com/industrial Interface interface.ti.com Medical www.ti.com/medical logic.ti.com Logic Security www.ti.com/security

Power Mgmt power.ti.com Space, Avionics and Defense www.ti.com/space-avionics-defense

Microcontrollers microcontroller.ti.com Video and Imaging www.ti.com/video

RFID www.ti-rfid.com

OMAP Applications Processors www.ti.com/omap TI E2E Community e2e.ti.com/omap

Wireless Connectivity <u>www.ti.com/wirelessconnectivity</u>